

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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EOL product

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# 2SK3461(L), 2SK3461(S)

Silicon N Channel Power MOS FET  
Power Switching

REJ03G1102-0300

Rev.3.00

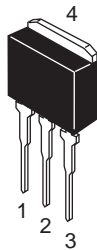
May 15, 2006

## Features

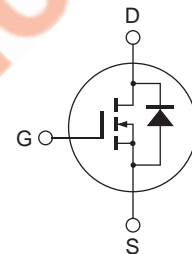
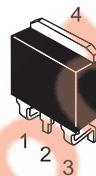
- Low on-resistance  
 $R_{DS(on)} = 4.3 \text{ m}\Omega$  typ.
- 4 V gate drive device
- High speed switching

## Outline

RENESAS Package code: PRSS0004AE-A  
(Package name: LDKPAK (L) )



RENESAS Package code: PRSS0004AE-B  
(Package name: LDKPAK (S)-(1) )



1. Gate
2. Drain
3. Source
4. Drain

## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	85	A
Drain peak current	I <sub>D (pulse)</sub> <sup>Note 1</sup>	340	A
Body-drain diode reverse drain current	I <sub>DR</sub>	85	A
Avalanche current	I <sub>AP</sub> <sup>Note 3</sup>	60	A
Avalanche energy	E <sub>AR</sub> <sup>Note 3</sup>	308	mJ
Channel dissipation	P <sub>ch</sub> <sup>Note 2</sup>	110	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%

2. Value at Ta = 25°C

3. Value at T<sub>ch</sub> = 25°C, R<sub>g</sub> ≥ 50 Ω

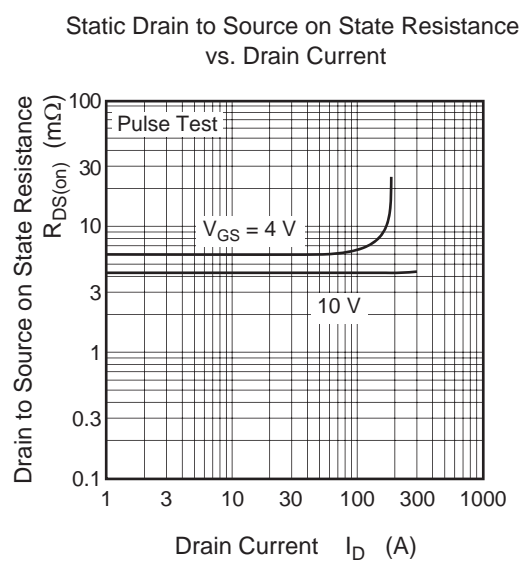
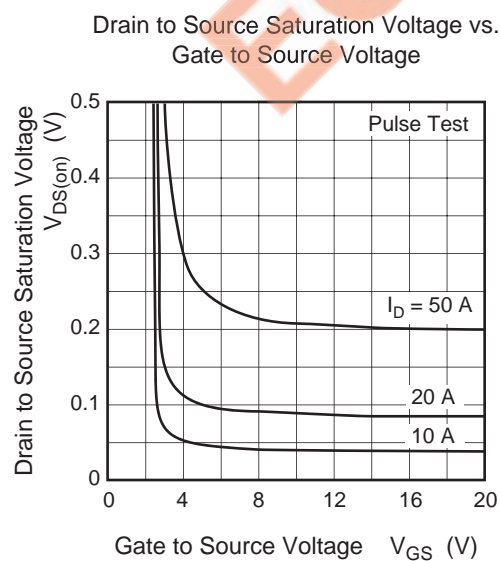
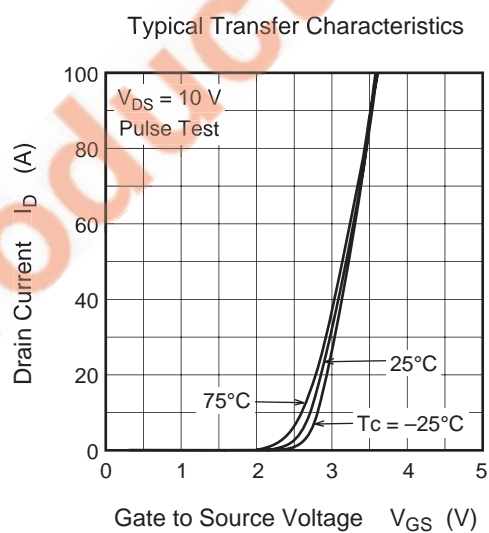
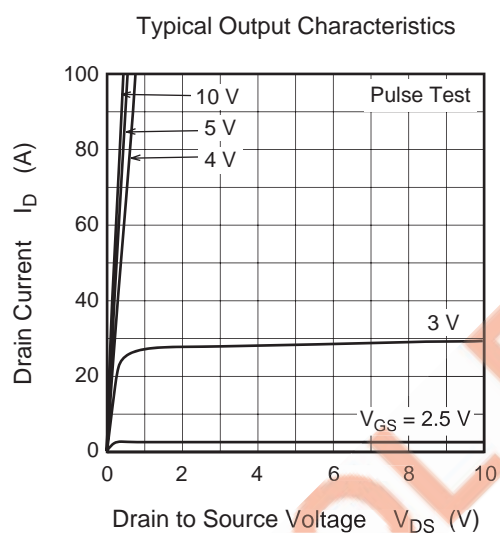
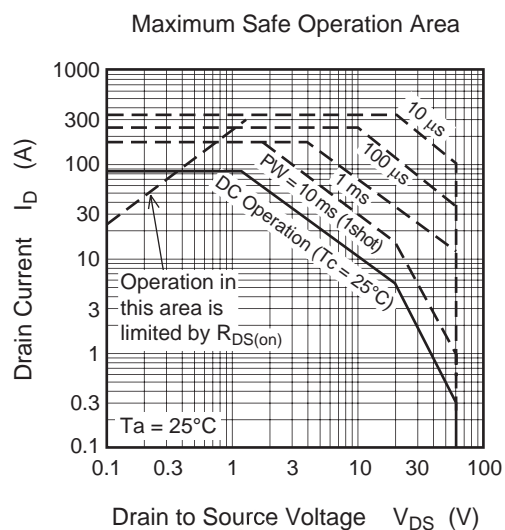
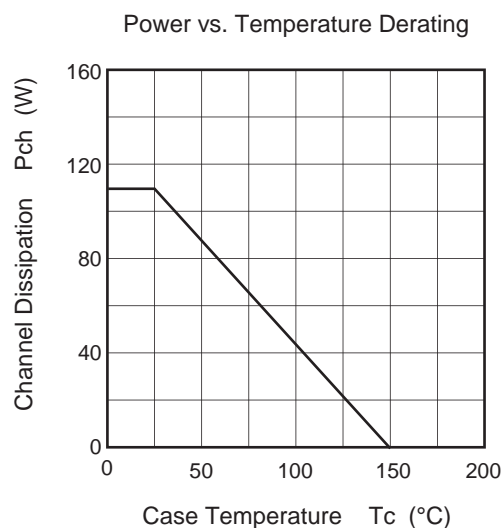
## Electrical Characteristics

(Ta = 25°C)

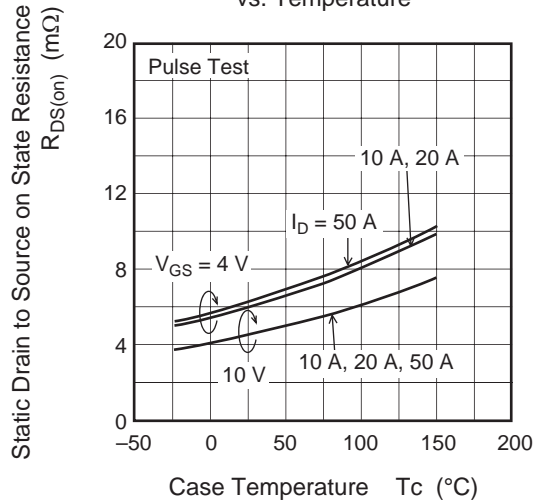
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR) DSS</sub>	60	—	—	V	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0
Zero gate voltage drain current	I <sub>DSS</sub>	—	—	10	μA	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0
Gate to source leak current	I <sub>GSS</sub>	—	—	±0.1	μA	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0
Gate to source cutoff voltage	V <sub>GS (off)</sub>	1.0	—	2.5	V	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA <sup>Note 4</sup>
Forward transfer admittance	y <sub>fs</sub>	55	90	—	S	I <sub>D</sub> = 45 A, V <sub>DS</sub> = 10 V <sup>Note 4</sup>
Static drain to source on state resistance	R <sub>DS (on)</sub>	—	4.3	5.5	mΩ	I <sub>D</sub> = 45 A, V <sub>GS</sub> = 10 V <sup>Note 4</sup>
	R <sub>DS (on)</sub>	—	6.0	9.0	mΩ	I <sub>D</sub> = 45 A, V <sub>GS</sub> = 4 V <sup>Note 4</sup>
Input capacitance	C <sub>iss</sub>	—	9770	—	pF	V <sub>DS</sub> = 10 V
Output capacitance	C <sub>oss</sub>	—	1340	—	pF	V <sub>GS</sub> = 0
Reverse transfer capacitance	C <sub>rss</sub>	—	470	—	pF	f = 1 MHz
Total gate charge	Q <sub>g</sub>	—	180	—	nC	V <sub>DD</sub> = 50 V
Gate to source charge	Q <sub>gs</sub>	—	32	—	nC	V <sub>GS</sub> = 10 V
Gate to drain charge	Q <sub>gd</sub>	—	36	—	nC	I <sub>D</sub> = 85 A
Turn-on delay time	t <sub>d (on)</sub>	—	53	—	ns	V <sub>GS</sub> = 10 V
Rise time	t <sub>r</sub>	—	320	—	ns	I <sub>D</sub> = 45 A
Turn-off delay time	t <sub>d (off)</sub>	—	700	—	ns	R <sub>L</sub> = 0.67 Ω
Fall time	t <sub>f</sub>	—	380	—	ns	
Body-drain diode forward voltage	V <sub>DF</sub>	—	1.0	—	V	I <sub>F</sub> = 85 A, V <sub>GS</sub> = 0
Body-drain diode reverse recovery time	t <sub>rr</sub>	—	70	—	ns	I <sub>F</sub> = 85 A, V <sub>GS</sub> = 0 di <sub>F</sub> /dt = 50 A/μs

Note: 4. Pulse test

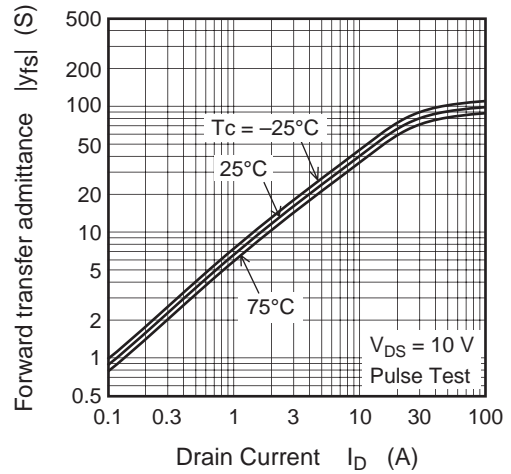
## Main Characteristics



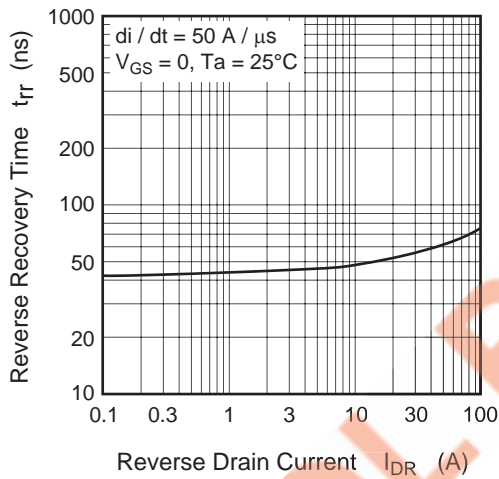
Static Drain to Source on State Resistance vs. Temperature



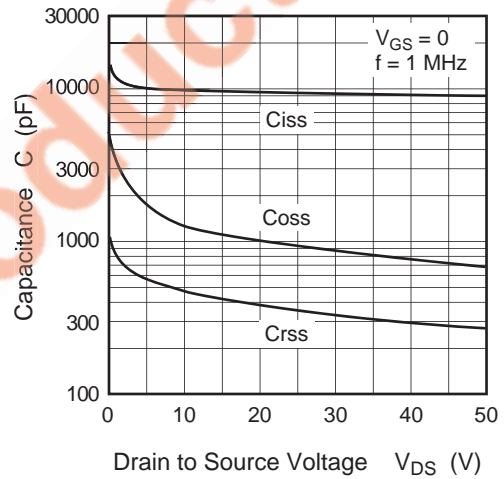
Forward Transfer Admittance vs. Drain Current



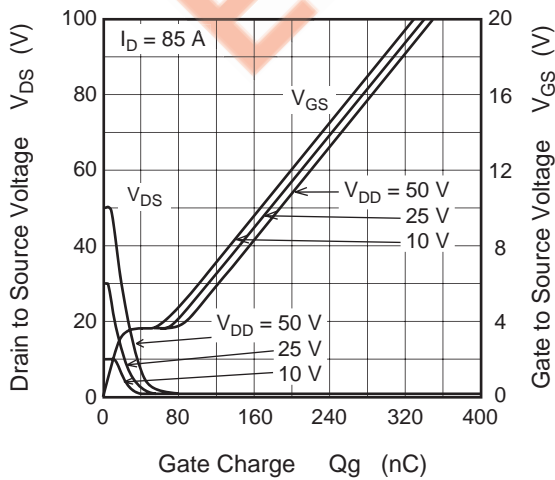
Body to Drain Diode Reverse Recovery Time



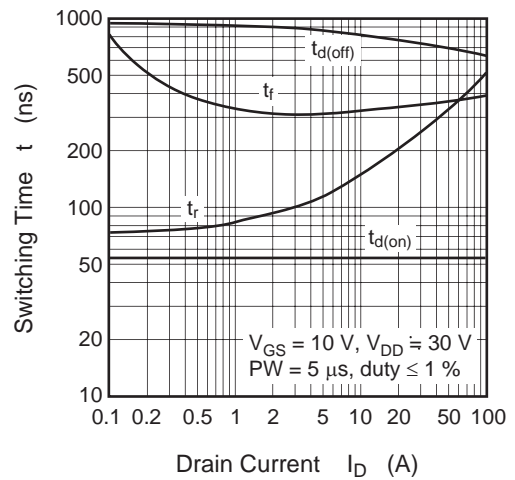
Typical Capacitance vs. Drain to Source Voltage

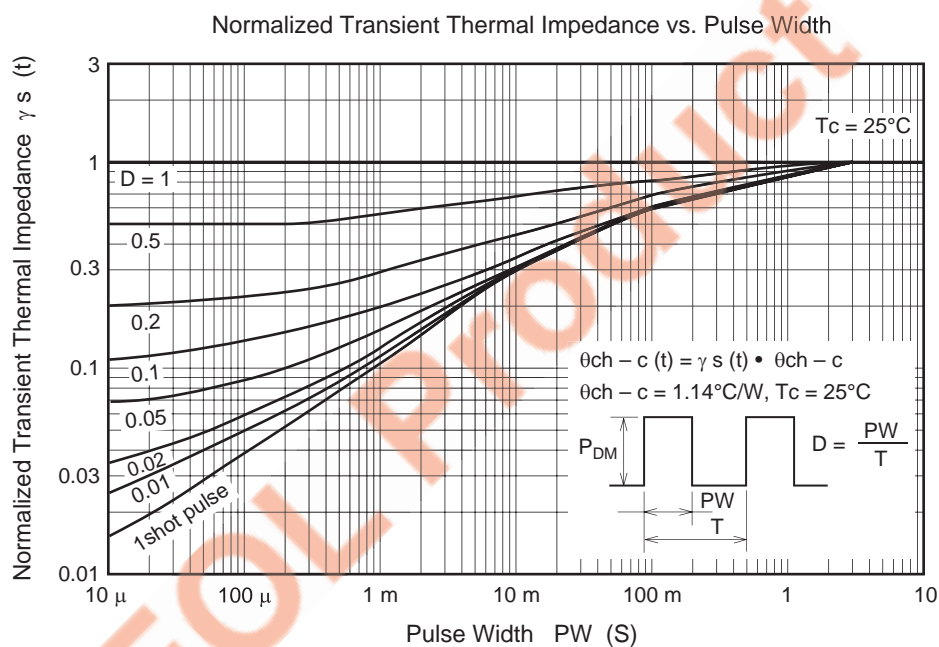
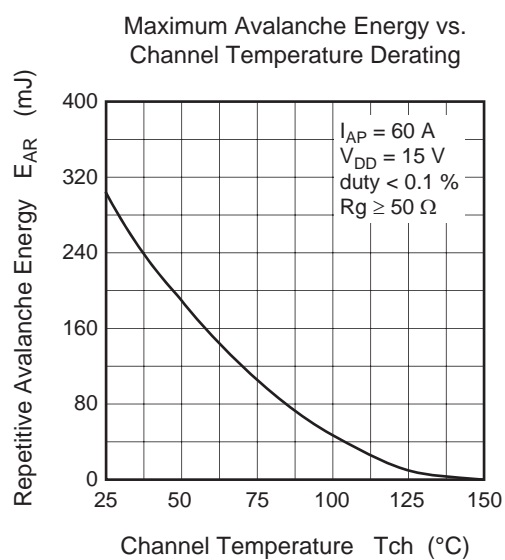
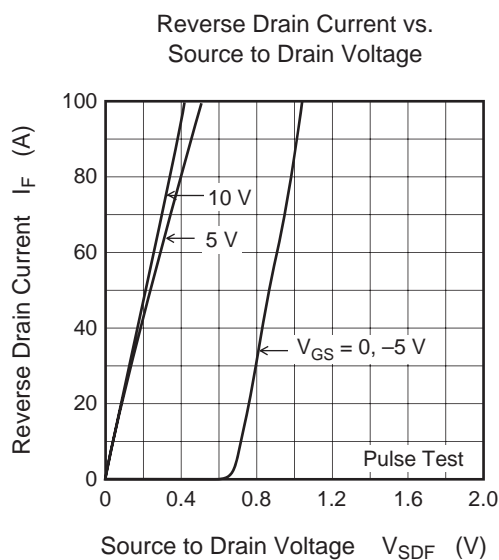


Dynamic Input Characteristics

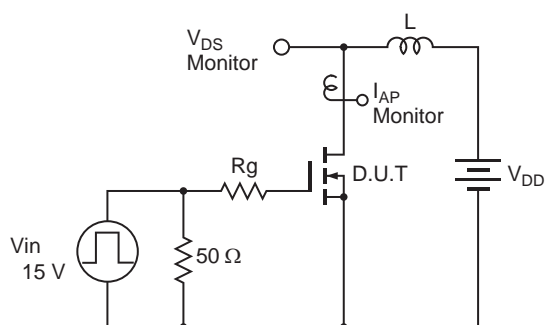


Switching Characteristics



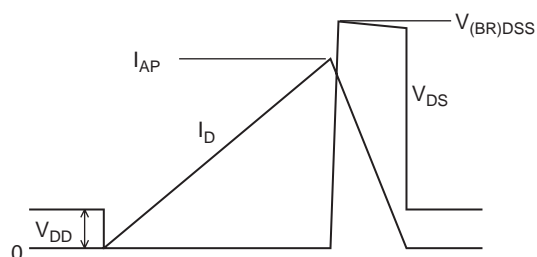


Avalanche Test Circuit

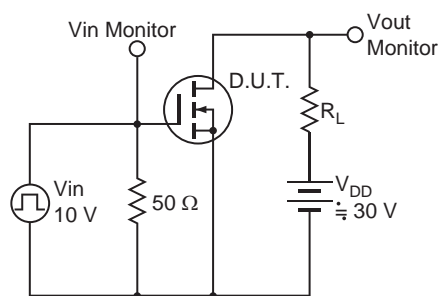


Avalanche Waveform

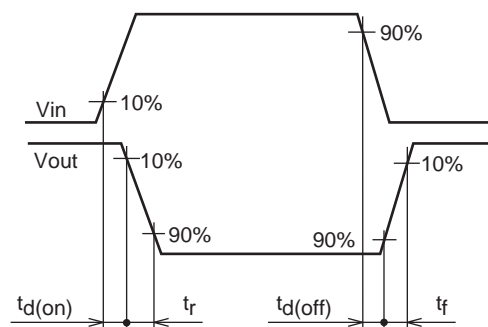
$$E_{AR} = \frac{1}{2} \cdot L \cdot I_{AP}^2 \cdot \frac{V_{DSS}}{V_{DSS} - V_{DD}}$$



Switching Time Test Circuit



Waveform

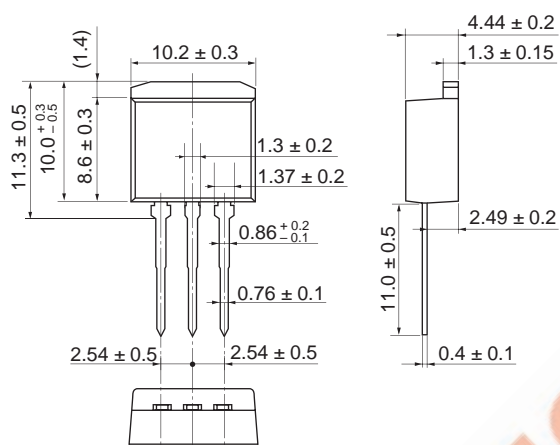


EOL Product

## Package Dimensions

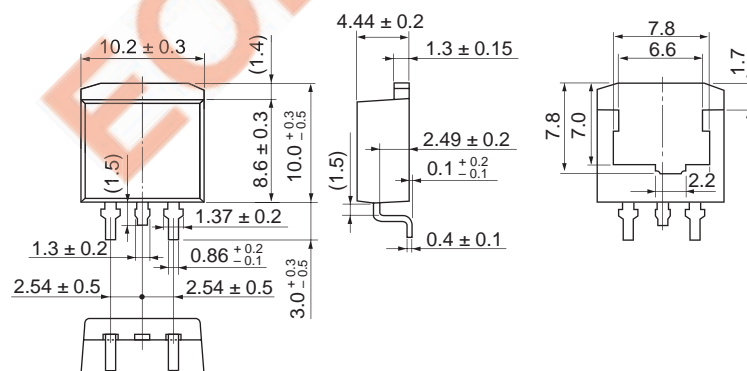
Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
LDBAK(L)	—	PRSS0004AE-A	LDBAK(L) / LDBAK(L)V	1.40g

Unit: mm



Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
LDBAK(S)-(1)	SC-83	PRSS0004AE-B	LDBAK(S)-(1) / LDBAK(S)-(1)V	1.30g

Unit: mm



### Ordering Information

Part Name	Quantity	Shipping Container
2SK3461L-E	500 pcs	Box (Sack)
2SK3461STL-E	1000 pcs	Taping

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